

# 256Mbit SDRAM

*4M x 16bit x 4 Banks*

*Synchronous DRAM*

*LVTTTL*

Revision 0.1

Aug. 2002

\* Samsung Electronics reserves the right to change products or specification without notice.

**Revision History**

**Revision 0.0 (Jan., 2002)**

-First generation

**Revision 0.1(Aug.,2002)**

- ICC6 of Low power is changed from 1.0 to 1.5 due to typo.

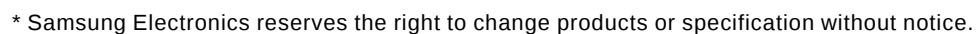
## CMOS SDRAM

## FEATURES

- ## GENERAL DESCRIPTION

## ORDERING INFORMATION

## FUNCTIONAL BLOCK DIAGRAM



## PIN CONFIGURATION (Top view)

|        |    |    |         |
|--------|----|----|---------|
| VDD    | 1  | 54 | VSS     |
| DQ0    | 2  | 53 | DQ15    |
| VDDQ   | 3  | 52 | VSSQ    |
| DQ1    | 4  | 51 | DQ14    |
| DQ2    | 5  | 50 | DQ13    |
| VSSQ   | 6  | 49 | VDDQ    |
| DQ3    | 7  | 48 | DQ12    |
| DQ4    | 8  | 47 | DQ11    |
| VDDQ   | 9  | 46 | VSSQ    |
| DQ5    | 10 | 45 | DQ10    |
| DQ6    | 11 | 44 | DQ9     |
| VSSQ   | 12 | 43 | VDDQ    |
| DQ7    | 13 | 42 | DQ8     |
| VDD    | 14 | 41 | VSS     |
| LDQM   | 15 | 40 | N.C/RFU |
| WE     | 16 | 39 | UDQM    |
| CAS    | 17 | 38 | CLK     |
| RAS    | 18 | 37 | CKE     |
| CS     | 19 | 36 | A12     |
| BA0    | 20 | 35 | A11     |
| BA1    | 21 | 34 | A9      |
| A10/AP | 22 | 33 | A8      |
| A0     | 23 | 32 | A7      |
| A1     | 24 | 31 | A6      |
| A2     | 25 | 30 | A5      |
| A3     | 26 | 29 | A4      |
| VDD    | 27 | 28 | VSS     |

54Pin TSOP (II)  
(400mil x 875mil)  
(0.8 mm Pin pitch)

## PIN FUNCTION DESCRIPTION

| Pin                     | Name                                      | Input Function                                                                                                                                                                          |
|-------------------------|-------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| CLK                     | System clock                              | Active on the positive going edge to sample all inputs.                                                                                                                                 |
| $\overline{\text{CS}}$  | Chip select                               | Disables or enables device operation by masking or enabling all inputs except CLK, CKE and DQM                                                                                          |
| CKE                     | Clock enable                              | Masks system clock to freeze operation from the next clock cycle.<br>CKE should be enabled at least one cycle prior to new command.<br>Disable input buffers for power down in standby. |
| A0 ~ A12                | Address                                   | Row/column addresses are multiplexed on the same pins.<br>Row address : RA0 ~ RA12, Column address : CA0 ~ CA8                                                                          |
| BA0 ~ BA1               | Bank select address                       | Selects bank to be activated during row address latch time.<br>Selects bank for read/write during column address latch time.                                                            |
| $\overline{\text{RAS}}$ | Row address strobe                        | Latches row addresses on the positive going edge of the CLK with $\overline{\text{RAS}}$ low.<br>Enables row access & precharge.                                                        |
| $\overline{\text{CAS}}$ | Column address strobe                     | Latches column addresses on the positive going edge of the CLK with $\overline{\text{CAS}}$ low.<br>Enables column access.                                                              |
| $\overline{\text{WE}}$  | Write enable                              | Enables write operation and row precharge.<br>Latches data in starting from $\overline{\text{CAS}}$ , $\overline{\text{WE}}$ active.                                                    |
| L(U)DQM                 | Data input/output mask                    | Makes data output Hi-Z, tSHZ after the clock and masks the output.<br>Blocks data input when L(U)DQM active.                                                                            |
| DQ0 ~ 15                | Data input/output                         | Data inputs/outputs are multiplexed on the same pins.                                                                                                                                   |
| VDD/VSS                 | Power supply/ground                       | Power and ground for the input buffers and the core logic.                                                                                                                              |
| VDDQ/VSSQ               | Data output power/ground                  | Isolated power supply and ground for the output buffers to provide improved noise immunity.                                                                                             |
| N.C/RFU                 | No connection<br>/reserved for future use | This pin is recommended to be left No Connection on the device.                                                                                                                         |

## ABSOLUTE MAXIMUM RATINGS

| Parameter                                         | Symbol                             | Value      | Unit |
|---------------------------------------------------|------------------------------------|------------|------|
| Voltage on any pin relative to Vss                | V <sub>IN</sub> , V <sub>OUT</sub> | -1.0 ~ 4.6 | V    |
| Voltage on V <sub>DD</sub> supply relative to Vss | V <sub>DD</sub> , V <sub>DDQ</sub> | -1.0 ~ 4.6 | V    |
| Storage temperature                               | T <sub>STG</sub>                   | -55 ~ +150 | °C   |
| Power dissipation                                 | P <sub>D</sub>                     | 1          | W    |
| Short circuit current                             | I <sub>OS</sub>                    | 50         | mA   |

**Note :** Permanent device damage may occur if "ABSOLUTE MAXIMUM RATINGS" are exceeded.  
Functional operation should be restricted to recommended operating condition.  
Exposure to higher than recommended voltage for extended periods of time could affect device reliability.

## DC OPERATING CONDITIONS

Recommended operating conditions (Voltage referenced to Vss = 0V, T<sub>A</sub> = -0 to 70°C)

| Parameter                 | Symbol                             | Min  | Typ | Max                  | Unit | Note                   |
|---------------------------|------------------------------------|------|-----|----------------------|------|------------------------|
| Supply voltage            | V <sub>DD</sub> , V <sub>DDQ</sub> | 3.0  | 3.3 | 3.6                  | V    | 4                      |
| Input logic high voltage  | V <sub>IH</sub>                    | 2.0  | 3.0 | V <sub>DD</sub> +0.3 | V    | 1                      |
| Input logic low voltage   | V <sub>IL</sub>                    | -0.3 | 0   | 0.8                  | V    | 2                      |
| Output logic high voltage | V <sub>OH</sub>                    | 2.4  | -   | -                    | V    | I <sub>OH</sub> = -2mA |
| Output logic low voltage  | V <sub>OL</sub>                    | -    | -   | 0.4                  | V    | I <sub>OL</sub> = 2mA  |
| Input leakage current     | I <sub>LI</sub>                    | -10  | -   | 10                   | uA   | 3                      |

**Notes :** 1. V<sub>IH</sub> (max) = 5.6V AC. The overshoot voltage duration is ≤ 3ns.  
2. V<sub>IL</sub> (min) = -2.0V AC. The undershoot voltage duration is ≤ 3ns.  
3. Any input 0V ≤ V<sub>IN</sub> ≤ V<sub>DDQ</sub>.  
Input leakage currents include Hi-Z output leakage for all bi-directional buffers with Tri-State outputs.  
4. The VDD condition of K4S561632C-60 is 3.135V~3.6V.

CAPACITANCE (V<sub>DD</sub> = 3.3V, T<sub>A</sub> = 23°C, f = 1MHz, V<sub>REF</sub> = 1.4V ± 200 mV)

| Pin                                | Symbol           | Min | Max | Unit | Note |
|------------------------------------|------------------|-----|-----|------|------|
| Clock                              | C <sub>CLK</sub> | 2.5 | 4.0 | pF   | 1    |
| RAS, CAS, WE, CS, CKE, DQM         | C <sub>IN</sub>  | 2.5 | 5.0 | pF   | 2    |
| Address                            | C <sub>ADD</sub> | 2.5 | 5.0 | pF   | 2    |
| DQ <sub>0</sub> ~ DQ <sub>15</sub> | C <sub>OUT</sub> | 4.0 | 6.5 | pF   | 3    |

**Notes :** 1. -75/7C only specify a maximum value of 3.5pF  
2. -75/7C only specify a maximum value of 3.8pF  
3. -75/7C only specify a maximum value of 6.0pF

## DC CHARACTERISTICS

(Recommended operating condition unless otherwise noted, TA = 0 to 70°C)

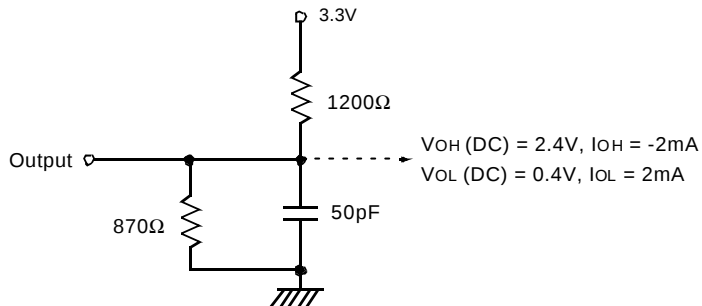
| Parameter                                                             | Symbol | Test Condition                                                                                               | Version |     |     |     |     | Unit | Note |   |
|-----------------------------------------------------------------------|--------|--------------------------------------------------------------------------------------------------------------|---------|-----|-----|-----|-----|------|------|---|
|                                                                       |        |                                                                                                              | -60     | -7C | -75 | -1H | -1L |      |      |   |
| Operating current<br>(One bank active)                                | ICC1   | Burst length = 1<br>trc ≥ trc(min)<br>Io = 0 mA                                                              | 150     | 110 | 100 | 100 | 100 | mA   | 1    |   |
| Precharge standby cur-<br>rent in power-down mode                     | ICC2P  | CKE ≤ VIL(max), tcc = 10ns                                                                                   | 2       |     |     |     |     | mA   |      |   |
|                                                                       | ICC2PS | CKE & CLK ≤ VIL(max), tcc = ∞                                                                                | 2       |     |     |     |     |      |      |   |
| Precharge standby cur-<br>rent in non power-down<br>mode              | ICC2N  | CKE ≥ VIH(min), $\overline{CS} \geq VIH(min)$ , tcc = 10ns<br>Input signals are changed one time during 20ns | 20      |     |     |     |     | mA   |      |   |
|                                                                       | ICC2NS | CKE ≥ VIH(min), CLK ≤ VIL(max), tcc = ∞<br>Input signals are stable                                          | 10      |     |     |     |     |      |      |   |
| Active standby current in<br>power-down mode                          | ICC3P  | CKE ≤ VIL(max), tcc = 10ns                                                                                   | 6       |     |     |     |     | mA   |      |   |
|                                                                       | ICC3PS | CKE & CLK ≤ VIL(max), tcc = ∞                                                                                | 6       |     |     |     |     |      |      |   |
| Active standby current in<br>non power-down mode<br>(One bank active) | ICC3N  | CKE ≥ VIH(min), $\overline{CS} \geq VIH(min)$ , tcc = 10ns<br>Input signals are changed one time during 20ns | 30      |     |     |     |     | mA   |      |   |
|                                                                       | ICC3NS | CKE ≥ VIH(min), CLK ≤ VIL(max), tcc = ∞<br>Input signals are stable                                          | 25      |     |     |     |     | mA   |      |   |
| Operating current<br>(Burst mode)                                     | ICC4   | Io = 0 mA<br>Page burst<br>4banks Activated.<br>tccd = 2CLKs                                                 | 180     | 140 | 140 | 130 | 130 | mA   | 1    |   |
| Refresh current                                                       | ICC5   | trc ≥ trc(min)                                                                                               | 220     | 220 | 200 | 190 | 190 | mA   | 2    |   |
| Self refresh current                                                  | ICC6   | CKE ≤ 0.2V                                                                                                   | C       | 3   |     |     |     |      | mA   | 3 |
|                                                                       |        |                                                                                                              | L       | 1.5 |     |     |     |      | mA   | 4 |

## Notes :

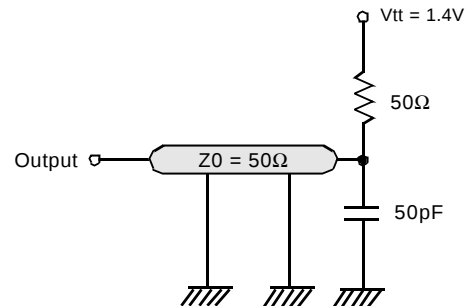
1. Measured with outputs open.
2. Refresh period is 64ms.
3. K4S561632D-TC\*\*
4. K4S561632D-TL\*\*
5. Unless otherwise noticed, input swing level is CMOS(VIH/VIL=VDDQ/VSSQ).

**AC OPERATING TEST CONDITIONS** ( $V_{DD} = 3.3V \pm 0.3V$ ,  $T_A = 0$  to  $70^\circ C$ )

| Parameter                                 | Value           | Unit |
|-------------------------------------------|-----------------|------|
| AC input levels ( $V_{ih}/V_{il}$ )       | 2.4/0.4         | V    |
| Input timing measurement reference level  | 1.4             | V    |
| Input rise and fall time                  | $t_r/t_f = 1/1$ | ns   |
| Output timing measurement reference level | 1.4             | V    |
| Output load condition                     | See Fig. 2      |      |



(Fig. 1) DC output load circuit



(Fig. 2) AC output load circuit

- Notes :** 1. The DC/AC Test Output Load of K4S561632C-TC(L)60 is 30pF.  
2. The  $V_{DD}$  condition of K4S561632C-TC(L)60 is 3.135V~3.6V.

**OPERATING AC PARAMETER**

(AC operating conditions unless otherwise noted)

| Parameter                                                |               | Symbol    | Version     |     |     |     |     | Unit | Note |
|----------------------------------------------------------|---------------|-----------|-------------|-----|-----|-----|-----|------|------|
|                                                          |               |           | -60         | -7C | -75 | -1H | -1L |      |      |
| Row active to row active delay                           |               | tRRD(min) | 12          | 15  | 15  | 20  | 20  | ns   | 1    |
| $\overline{\text{RAS}}$ to $\overline{\text{CAS}}$ delay |               | tRCD(min) | 18          | 15  | 20  | 20  | 20  | ns   | 1    |
| Row precharge time                                       |               | tRP(min)  | 18          | 15  | 20  | 20  | 20  | ns   | 1    |
| Row active time                                          |               | tRAS(min) | 42          | 45  | 45  | 50  | 50  | ns   | 1    |
|                                                          |               | tRAS(max) | 100         |     |     |     |     | us   |      |
| Row cycle time                                           |               | tRC(min)  | 60          | 60  | 65  | 70  | 70  | ns   | 1    |
| Last data in to row precharge                            |               | tRDL(min) | 2           |     |     |     |     | CLK  | 2, 5 |
| Last data in to Active delay                             |               | tDAL(min) | 2 CLK + tRP |     |     |     |     | -    | 5    |
| Last data in to new col. address delay                   |               | tCDL(min) | 1           |     |     |     |     | CLK  | 2    |
| Last data in to burst stop                               |               | tBDL(min) | 1           |     |     |     |     | CLK  | 2    |
| Col. address to col. address delay                       |               | tCCD(min) | 1           |     |     |     |     | CLK  | 3    |
| Number of valid output data                              | CAS latency=3 | 2         |             |     |     |     | ea  | 4    |      |
|                                                          | CAS latency=2 | -         | 1           |     |     |     |     |      |      |

- Notes :** 1. The minimum number of clock cycles is determined by dividing the minimum time required with clock cycle time and then rounding off to the next higher integer.  
2. Minimum delay is required to complete write.  
3. All parts allow every cycle column address change.  
4. In case of row precharge interrupt, auto precharge and read burst stop.  
5. In 100MHz and below 100MHz operating conditions,  $t_{RDL}=1CLK$  and  $t_{DAL}=1CLK + 20ns$  is also supported. SAMSUNG recommends  $t_{RDL}=2CLK$  and  $t_{DAL}=2CLK + t_{RP}$ .

**AC CHARACTERISTICS** (AC operating conditions unless otherwise noted)

| Parameter                 |               | Symbol | -60 |      | -7C |      | -75 |      | -1H |      | -1L |      | Unit | Note |
|---------------------------|---------------|--------|-----|------|-----|------|-----|------|-----|------|-----|------|------|------|
|                           |               |        | Min | Max  | Min | Max  | Min | Max  | Min | Max  | Min | Max  |      |      |
| CLK cycle time            | CAS latency=3 | tcc    | 6   | 1000 | 7.5 | 1000 | 7.5 | 1000 | 10  | 1000 | 10  | 1000 | ns   | 1    |
|                           | CAS latency=2 |        | -   |      | 7.5 |      | 10  |      | 10  |      | 12  |      |      |      |
| CLK to valid output delay | CAS latency=3 | tsac   |     | 5    |     | 5.4  |     | 5.4  |     | 6    |     | 6    | ns   | 1,2  |
|                           | CAS latency=2 |        |     | -    |     | 5.4  |     | 6    |     | 6    |     | 7    |      |      |
| Output data hold time     | CAS latency=3 | toH    | 2.5 |      | 3   |      | 3   |      | 3   |      | 3   |      | ns   | 2    |
|                           | CAS latency=2 |        | -   |      | 3   |      | 3   |      | 3   |      | 3   |      |      |      |
| CLK high pulse width      |               | tCH    | 2.5 |      | 2.5 |      | 2.5 |      | 3   |      | 3   |      | ns   | 3    |
| CLK low pulse width       |               | tCL    | 2.5 |      | 2.5 |      | 2.5 |      | 3   |      | 3   |      | ns   | 3    |
| Input setup time          |               | tSS    | 1.5 |      | 1.5 |      | 1.5 |      | 2   |      | 2   |      | ns   | 3    |
| Input hold time           |               | tSH    | 1   |      | 0.8 |      | 0.8 |      | 1   |      | 1   |      | ns   | 3    |
| CLK to output in Low-Z    |               | tSLZ   | 1   |      | 1   |      | 1   |      | 1   |      | 1   |      | ns   | 2    |
| CLK to output in Hi-Z     | CAS latency=3 | tSHZ   |     | 5    |     | 5.4  |     | 5.4  |     | 6    |     | 6    | ns   |      |
|                           | CAS latency=2 |        |     | -    |     | 5.4  |     | 6    |     | 6    |     | 7    |      |      |

- Notes :**
- Parameters depend on programmed CAS latency.
  - If clock rising time is longer than 1ns, (tr/2-0.5)ns should be added to the parameter.
  - Assumed input rise and fall time (tr & tf) = 1ns.  
If tr & tf is longer than 1ns, transient time compensation should be considered,  
i.e., [(tr + tf)/2-1]ns should be added to the parameter.

**DQ BUFFER OUTPUT DRIVE CHARACTERISTICS**

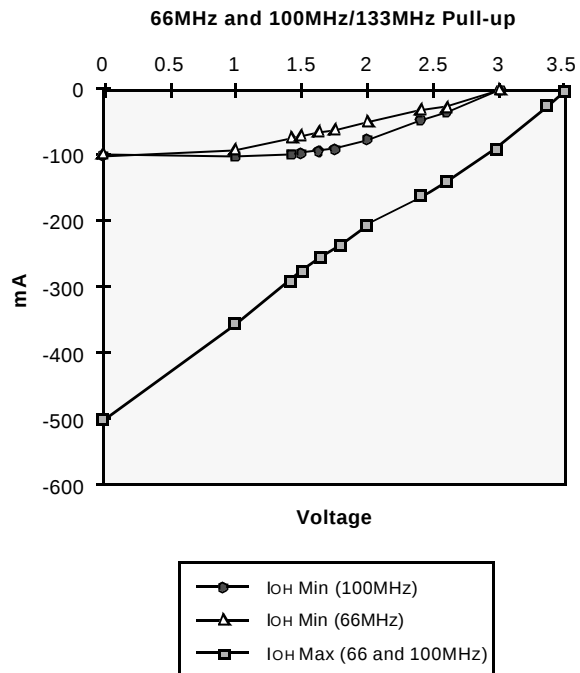
| Parameter        | Symbol | Condition                              | Min  | Typ | Max  | Unit     | Notes |
|------------------|--------|----------------------------------------|------|-----|------|----------|-------|
| Output rise time | trh    | Measure in linear region : 1.2V ~ 1.8V | 1.37 |     | 4.37 | Volts/ns | 3     |
| Output fall time | tfh    | Measure in linear region : 1.2V ~ 1.8V | 1.30 |     | 3.8  | Volts/ns | 3     |
| Output rise time | trh    | Measure in linear region : 1.2V ~ 1.8V | 2.8  | 3.9 | 5.6  | Volts/ns | 1,2   |
| Output fall time | tfh    | Measure in linear region : 1.2V ~ 1.8V | 2.0  | 2.9 | 5.0  | Volts/ns | 1,2   |

- Notes :**
- Rise time specification based on 0pF + 50 Ω to Vss, use these values to design to.
  - Fall time specification based on 0pF + 50 Ω to VDD, use these values to design to.
  - Measured into 50pF only, use these values to characterize to.
  - All measurements done with respect to Vss.

## IBIS SPECIFICATION

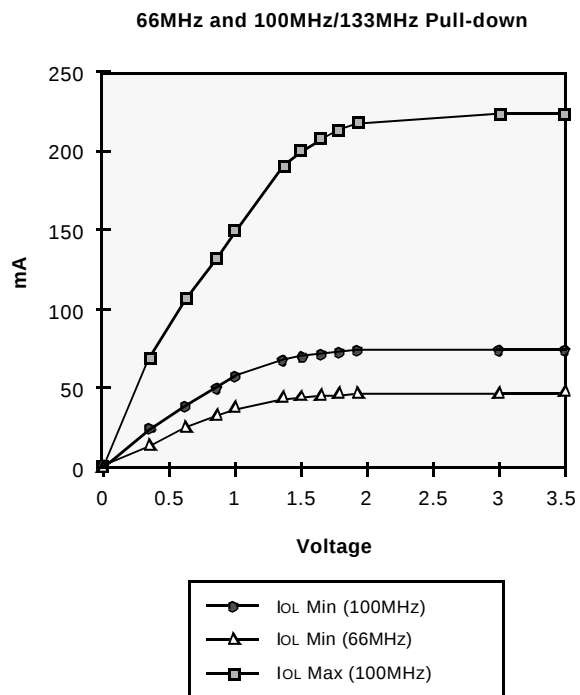
## IOH Characteristics (Pull-up)

| Voltage | 100MHz<br>133MHz<br>Min | 100MHz<br>133MHz<br>Max | 66MHz<br>Min |
|---------|-------------------------|-------------------------|--------------|
| (V)     | I (mA)                  | I (mA)                  | I (mA)       |
| 3.45    |                         | -2.4                    |              |
| 3.3     |                         | -27.3                   |              |
| 3.0     | 0.0                     | -74.1                   | -0.7         |
| 2.6     | -21.1                   | -129.2                  | -7.5         |
| 2.4     | -34.1                   | -153.3                  | -13.3        |
| 2.0     | -58.7                   | -197.0                  | -27.5        |
| 1.8     | -67.3                   | -226.2                  | -35.5        |
| 1.65    | -73.0                   | -248.0                  | -41.1        |
| 1.5     | -77.9                   | -269.7                  | -47.9        |
| 1.4     | -80.8                   | -284.3                  | -52.4        |
| 1.0     | -88.6                   | -344.5                  | -72.5        |
| 0.0     | -93.0                   | -502.4                  | -93.0        |



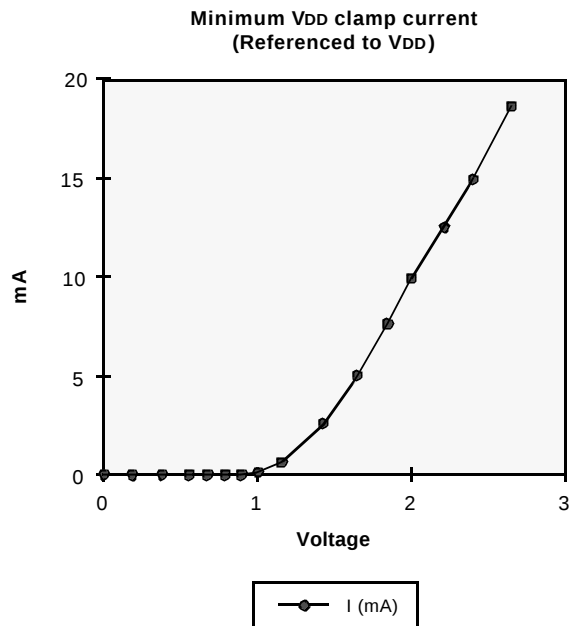
## IOL Characteristics (Pull-down)

| Voltage | 100MHz<br>133MHz<br>Min | 100MHz<br>133MHz<br>Max | 66MHz<br>Min |
|---------|-------------------------|-------------------------|--------------|
| (V)     | I (mA)                  | I (mA)                  | I (mA)       |
| 0.0     | 0.0                     | 0.0                     | 0.0          |
| 0.4     | 27.5                    | 70.2                    | 17.7         |
| 0.65    | 41.8                    | 107.5                   | 26.9         |
| 0.85    | 51.6                    | 133.8                   | 33.3         |
| 1.0     | 58.0                    | 151.2                   | 37.6         |
| 1.4     | 70.7                    | 187.7                   | 46.6         |
| 1.5     | 72.9                    | 194.4                   | 48.0         |
| 1.65    | 75.4                    | 202.5                   | 49.5         |
| 1.8     | 77.0                    | 208.6                   | 50.7         |
| 1.95    | 77.6                    | 212.0                   | 51.5         |
| 3.0     | 80.3                    | 219.6                   | 54.2         |
| 3.45    | 81.4                    | 222.6                   | 54.9         |

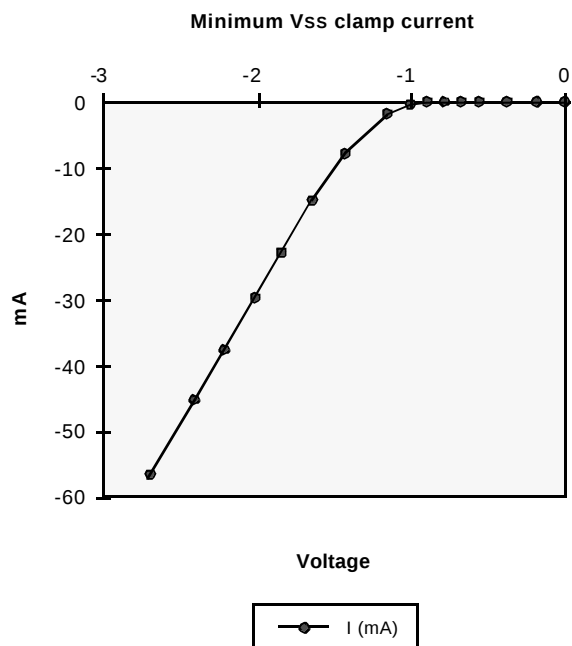


**V<sub>DD</sub> Clamp @ CLK, CKE,  $\overline{\text{CS}}$ , DQM & DQ**

| V <sub>DD</sub> (V) | I (mA) |
|---------------------|--------|
| 0.0                 | 0.0    |
| 0.2                 | 0.0    |
| 0.4                 | 0.0    |
| 0.6                 | 0.0    |
| 0.7                 | 0.0    |
| 0.8                 | 0.0    |
| 0.9                 | 0.0    |
| 1.0                 | 0.23   |
| 1.2                 | 1.34   |
| 1.4                 | 3.02   |
| 1.6                 | 5.06   |
| 1.8                 | 7.35   |
| 2.0                 | 9.83   |
| 2.2                 | 12.48  |
| 2.4                 | 15.30  |
| 2.6                 | 18.31  |

**V<sub>SS</sub> Clamp @ CLK, CKE,  $\overline{\text{CS}}$ , DQM & DQ**

| V <sub>SS</sub> (V) | I (mA) |
|---------------------|--------|
| -2.6                | -57.23 |
| -2.4                | -45.77 |
| -2.2                | -38.26 |
| -2.0                | -31.22 |
| -1.8                | -24.58 |
| -1.6                | -18.37 |
| -1.4                | -12.56 |
| -1.2                | -7.57  |
| -1.0                | -3.37  |
| -0.9                | -1.75  |
| -0.8                | -0.58  |
| -0.7                | -0.05  |
| -0.6                | 0.0    |
| -0.4                | 0.0    |
| -0.2                | 0.0    |
| 0.0                 | 0.0    |



## SIMPLIFIED TRUTH TABLE

| Command                            |                        |       | CKEn-1 | CKEn | $\overline{CS}$ | $\overline{RAS}$ | $\overline{CAS}$ | $\overline{WE}$ | DQM | BA0,1   | A10/AP      | A11,A12,<br>A9 ~ A0                                  | Note |
|------------------------------------|------------------------|-------|--------|------|-----------------|------------------|------------------|-----------------|-----|---------|-------------|------------------------------------------------------|------|
| Register                           | Mode register set      |       | H      | X    | L               | L                | L                | L               | X   | OP code |             |                                                      | 1,2  |
| Refresh                            | Auto refresh           |       | H      | H    | L               | L                | L                | H               | X   | X       |             |                                                      | 3    |
|                                    | Self refresh           | Entry |        | L    |                 |                  |                  |                 |     |         |             |                                                      | 3    |
|                                    |                        | Exit  | L      | H    | L               | H                | H                | H               | X   | X       |             |                                                      | 3    |
|                                    |                        |       |        |      | H               | X                | X                | X               |     |         |             |                                                      | 3    |
| Bank active & row addr.            |                        |       | H      | X    | L               | L                | H                | H               | X   | V       | Row address |                                                      |      |
| Read & column address              | Auto precharge disable |       | H      | X    | L               | H                | L                | H               | X   | V       | L           | Column address<br>(A <sub>0</sub> ~ A <sub>6</sub> ) | 4    |
|                                    | Auto precharge enable  |       |        |      |                 |                  |                  |                 |     |         | H           |                                                      | 4,5  |
| Write & column address             | Auto precharge disable |       | H      | X    | L               | H                | L                | L               | X   | V       | L           | Column address<br>(A <sub>0</sub> ~ A <sub>6</sub> ) | 4    |
|                                    | Auto precharge enable  |       |        |      |                 |                  |                  |                 |     |         | H           |                                                      | 4,5  |
| Burst stop                         |                        |       | H      | X    | L               | H                | H                | L               | X   | X       |             |                                                      | 6    |
| Precharge                          | Bank selection         |       | H      | X    | L               | L                | H                | L               | X   | V       | L           | X                                                    |      |
|                                    | All banks              |       |        |      |                 |                  |                  |                 |     | X       | H           |                                                      |      |
| Clock suspend or active power down |                        | Entry | H      | L    | H               | X                | X                | X               | X   | X       |             |                                                      |      |
|                                    |                        |       |        |      | L               | V                | V                | V               |     |         |             |                                                      |      |
|                                    |                        | Exit  | L      | H    | X               | X                | X                | X               | X   | X       |             |                                                      |      |
|                                    |                        |       |        |      |                 |                  |                  |                 |     |         |             |                                                      |      |
| Precharge power down mode          |                        | Entry | H      | L    | H               | X                | X                | X               | X   | X       |             |                                                      |      |
|                                    |                        |       |        |      | L               | H                | H                | H               |     |         |             |                                                      |      |
|                                    |                        | Exit  | L      | H    | H               | X                | X                | X               | X   |         |             |                                                      |      |
|                                    |                        |       |        |      | L               | V                | V                | V               |     |         |             |                                                      |      |
| DQM                                |                        |       | H      | X    |                 |                  |                  |                 | V   | X       |             |                                                      | 7    |
| No operation command               |                        |       | H      | X    | H               | X                | X                | X               | X   | X       |             |                                                      |      |
|                                    |                        |       |        |      | L               | H                | H                | H               |     |         |             |                                                      |      |

(V=Valid, X=Don't care, H=Logic high, L=Logic low)

**Notes :** 1. OP Code : Operand codeA<sub>0</sub> ~ A<sub>11</sub> & BA<sub>0</sub> ~ BA<sub>1</sub> : Program keys. (@ MRS)

2. MRS can be issued only at all banks precharge state.

A new command can be issued after 2 CLK cycles of MRS.

3. Auto refresh functions are as same as CBR refresh of DRAM.

The automatical precharge without row precharge command is meant by "Auto".

Auto/self refresh can be issued only at all banks precharge state.

4. BA<sub>0</sub> ~ BA<sub>1</sub> : Bank select addresses.If both BA<sub>0</sub> and BA<sub>1</sub> are "Low" at read, write, row active and precharge, bank A is selected.If BA<sub>0</sub> is "High" and BA<sub>1</sub> is "Low" at read, write, row active and precharge, bank B is selected.If BA<sub>0</sub> is "Low" and BA<sub>1</sub> is "High" at read, write, row active and precharge, bank C is selected.If both BA<sub>0</sub> and BA<sub>1</sub> are "High" at read, write, row active and precharge, bank D is selected.If A<sub>10</sub>/AP is "High" at row precharge, BA<sub>0</sub> and BA<sub>1</sub> is ignored and all banks are selected.

5. During burst read or write with auto precharge, new read/write command can not be issued.

Another bank read/write command can be issued after the end of burst.

New row active of the associated bank can be issued at t<sub>RP</sub> after the end of burst.

6. Burst stop command is valid at every burst length.

7. DQM sampled at positive going edge of a CLK and masks the data-in at the very CLK (Write DQM latency is 0),

but makes Hi-Z state the data-out of 2 CLK cycles after. (Read DQM latency is 2)

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